

	Type	L #	Hits	Search Text	DBs
1	BRS	L1	640	transistor same (surface adj tension)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB
2	BRS	L2	264	1 not ink	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB
3	BRS	L3	6429	(source or drain) same (surface adj tension)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB
4	BRS	L4	437796	"257"/\$.ccls. or "438"/\$.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB
5	BRS	L5	368	3 and 4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB
6	BRS	L6	339	5 not ink	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM TDB
7	BRS	L7	177282	(insulating adj layer) or insulator	USPAT
8	BRS	L8	73	7 with (surface adj tension)	USPAT